

Trans IGBT Chip N-CH 1700V 200A 1040mW 3-Pin(3+Tab) PLUS 247

Manufacturer: <u>Littelfuse Inc</u>

Package/Case: PLUS247

Product Type: Thyristors

Lifecycle: Active



Images are for reference only

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General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features	Application
High blocking voltage	Radar transmitter power supplies
High power density	Radar pulse modulators
High current handling capability	Capacitor discharge circuits
Low conduction losses	
MOS gate turn on for drive simplicity	High voltage power supplies
International standard and proprietary ISOPLUSTM packages	AC switches
Benefits:	HV circuit breakers
Eliminates multiple series-parallel lower voltage, lower current rateddevices	Pulser circuits
Simpler system design	High voltage test equipment
Improved reliability	riigii voitage test equipinent
Reduced component count	Laser & X-ray generators
Reduced system cost	

Recommended For You

IXGH48N60C3D1 IXYX100N120C3

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IXGH30N60B2D1

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TO-247 MODULE TO-247

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